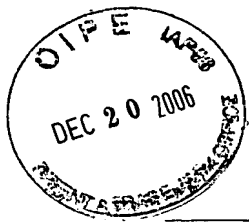


JPW



Docket No. 8733.913.00
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Sang-Hyun KIM

Customer No. 30827

Application No. 10/663,805

Confirmation No. 3765

Filed: September 17, 2003

Art Unit: 1763

For: FABRICATION METHOD OF
POLYCRYSTALLINE SILICON TFT

Examiner: George A. Goudreau

MS Amendment

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

AMENDMENT

Sir:

In response to the Office Action dated September 20, 2006, please amend the above-identified application as follows:

INTRODUCTORY COMMENTS

Amendments to the Claims begins on page 2 of this paper.

Remarks begin on page 7 of this paper.